



10/ 075 390

CAC

Docket No.: M4065.0505/P505
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Letters Patent of:
Kristy A. Campbell et al.

Patent No.: 6,867,064

Issued: March 15, 2005

For: METHOD TO ALTER CHALCOGENIDE
GLASS FOR IMPROVED SWITCHING
CHARACTERISTICS

Certificate
SEP 01 2005
of Correction

REQUEST TO CORRECT A CERTIFICATE OF CORRECTION PURSUANT
TO 37 CFR 1.322

Attention: Certificate of Correction Branch
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

Upon reviewing the attached Certificate of Correction for the above-identified patent, Patentees noted a typographical error. The following correction, listed on the original Request for Correction (copy attached), is still in error.

At page 7, column 2, "Yoji Kowamoto et al." reference, "Ionic Conduction in $\text{As}_2\text{S}_3\text{-Ag}_2\text{S, GeS}_5\text{GeS-Ag}_2\text{S}$ and $\text{P}_2\text{S}_5\text{-Ag}_2\text{S}$ Glasses," Journal of Non-Crystalline Solids 20 (1976), pgs. 393-404." should read: --Yoji Kawamoto et al. -"Ionic Conduction in $\text{As}_2\text{S}_3\text{-Ag}_2\text{S, GeS}_2\text{GeS-Ag}_2\text{S}$ and $\text{P}_2\text{S}_5\text{-Ag}_2\text{S}$ Glasses," Journal of Non-Crystalline Solids 20 (1976), pgs. 393-404.

Transmitted herewith is a proposed Certificate of Correction effecting such amendment. Patentees respectfully solicit the granting of the requested corrected Certificate of Correction and believe no fee is involved.

SEP 06 2005

Patent No.: 6,867,064

Docket No.: M4065.0505/P505

Dated: August 29, 2005

Respectfully submitted,

By 

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UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 6,867,064 B2
DATED : March 15, 2005
INVENTOR(S) : Kristy A. Campbell et al.

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Title page.

Item [56], **References Cited**, U.S. PATENT DOCUMENTS, "5,335,519 A 8/1994 Bernie" should read -- 5,335,219 8/1994 Ovshinsky et al. --
OTHER PUBLICATIONS, "El Bouchairi, B.; Bernede, J.C.; reference, "El Bouchairi, B.; Bernede, J.C.; Burgaud, P., Properties of $\text{Ag}_{2-x}\text{Se}_{1+x/n}\text{-Si}$ diodes, Thin Solid Films 110 (1983) 107-113." should read -- El Bouchairi, B.; Bernede, J.C.; Burgaud, P., Properties of $\text{Ag}_{2-x}\text{Se}_{1+x/n}\text{-Si}$ diodes, Thin Solid Films 110 (1983) 107-113. --
"Feng, X.; Bresser," reference "Feng, X.; Bresser, W.J.; Boolchand, P., Directed evidence for stiffness threshold in Chalcogenide glasses, Phys. Rev. Lett. 78 (1997) 4422-4425." should read -- Feng, X.; Bresser, W.J.; Boolchand, P., Direct evidence for stiffness threshold in chalcogenide glasses, Phys. Rev. Lett. 78 (1997) 4422-4425. --
"Hosokawa, S., reference, "Hosokawa, S., Atomic and electronic structures of glassy $\text{Ge}_{x}\text{Se}_{1-x}$ around the stiffness threshold composition, J. Optoelectronics and Advanced Materials 3 (2001) 199-214." should read -- Hosokawa, S., Atomic and electronic structures of glassy $\text{Ge}_{x}\text{Se}_{1-x}$ around the stiffness threshold composition, J. Optoelectronics and Advanced Materials 3 (2001) 199-214. --
"Mitokova, M.; Wang, Y Boolchand, P.," reference Dual chemical role of Ag as an additive in chalcogenide glasses Phys. Rev. Lett. 83 (1999) 3848-3851." should read -- Mitkova, M.; Wang, Y.; Boolchand, P., Dual chemical role of Ag as an additive in chalcogenide glasses, Phys. Rev. Lett. 83 (1999) 3848- 3851. --
"Yoji Kawamoto et al." reference, "Ionic Conduction in $\text{As}_2\text{S}_3\text{-Ag}_2\text{S}$, $\text{GeS}_2\text{-GeS-Ag}_2\text{S}$ and $\text{P}_2\text{S}_5\text{-Ag}_2\text{S}$ Glasses," Journal of Non-Crystalline Solids 20 (1976), pgs. 393-404." should read -- Yoji Kawamoto et al., "Ionic Conduction in $\text{As}_2\text{S}_3\text{-Ag}_2\text{S}$, $\text{GeS}_2\text{-Ag}_2\text{S}$ and $\text{P}_2\text{S}_5\text{-Ag}_2\text{S}$ Glasses," Journal of Non-Crystalline Solids 20 (1976), pgs. 393-404. --

Signed and Sealed this

Twenty-eighth Day of June, 2005



JON W. DUDAS

Director of the United States Patent and Trademark Office

**UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION**

Page 1 of 1

PATENT NO. : 6,867,064
APPLICATION NO. : 10/075,390
ISSUE DATE : March 15, 2005
INVENTOR(S) : Kristy A. Campbell et al.

It is certified that an error appears or errors appear in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

In OTHER PUBLICATIONS:

At page 7, column 2, "Yoji Kowamoto et al." reference, "Ionic Conduction in As_2S_3 - Ag_2S , GeS_5GeS - Ag_2S and P_2S_5 - Ag_2S Glasses," Journal of Non-Crystalline Solids 20 (1976), pgs. 393-404." should read: --Yoji Kawamoto et al. -"Ionic Conduction in As_2S_3 - Ag_2S , GeS_2GeS - Ag_2S and P_2S_5 - Ag_2S Glasses," Journal of Non-Crystalline Solids 20 (1976), pgs. 393-404.

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SEP 06 2005